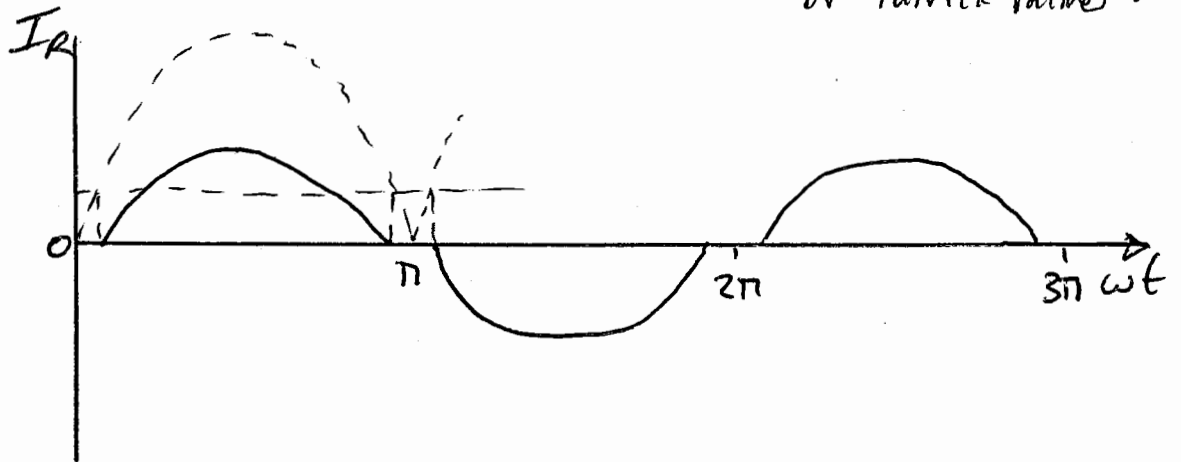


1/ (a)



12.9V is the average after diodes. (2V)

∴ 14.9V before the diodes ignoring small loss of conduction angle.

$$\therefore \frac{2\sqrt{2}\hat{V}}{\pi} = 14.9 \quad \hat{V} = 23.4V$$

For conduction angle θ

$$23.4 \sin \theta = 3.6 + 2 \times 1 \text{ — diode voltages.}$$

$$\theta = 13.9^\circ$$

So conduction over 152.2° A similar

(8.46ms) answer is found ignoring the diode's voltages

$$\frac{2}{\pi} \int_{13.9^\circ}^{90^\circ} 23.4 \sin \omega t \, d\omega t = 14.46V \text{ — close to } 14.9V!$$

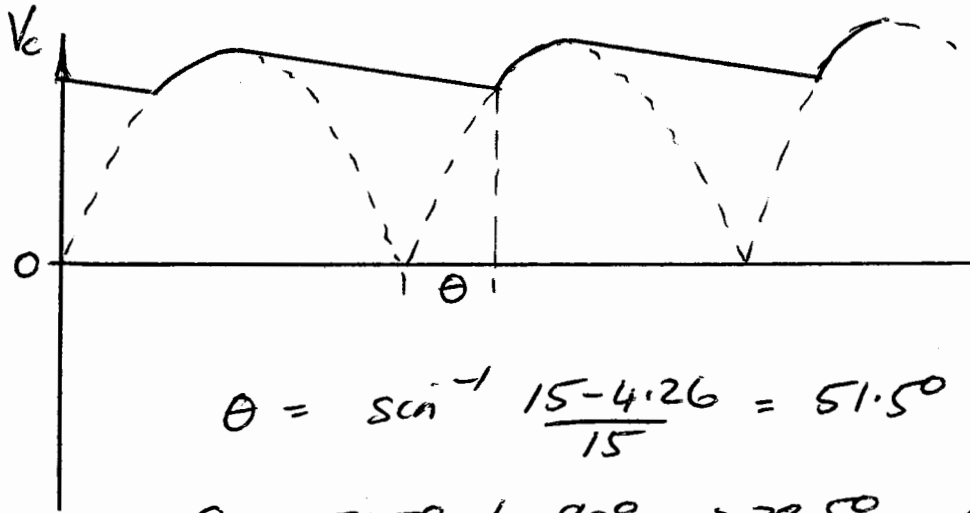
$$\frac{14.46 - 5.6}{R} = 0.5 \quad R = \underline{17.72 \Omega}$$

Safe, Cheap, Reliable, Low peak current, good pt,
Low harmonic distortion, Any 3!

1, (b) Capacitively smoothed!

$$I = C \frac{dV}{dt} \quad \Delta V = \frac{0.2 \times 10m}{0.47m} = 4.26V$$

$12\sqrt{2} - 2$ diodes $\Rightarrow 15V$



$$\theta = \sin^{-1} \frac{15 - 4.26}{15} = 51.5^\circ$$

Say 51.5° to $90^\circ \Rightarrow 38.5^\circ$ or $2.14ms$

$$I = C \frac{dV}{dt} = C \omega \hat{V} \cos \omega t \Big|_{\omega t = 51.5^\circ}$$

$$= 470\mu \cdot 2\pi \cdot 50 \cdot 15 \times 0.622$$

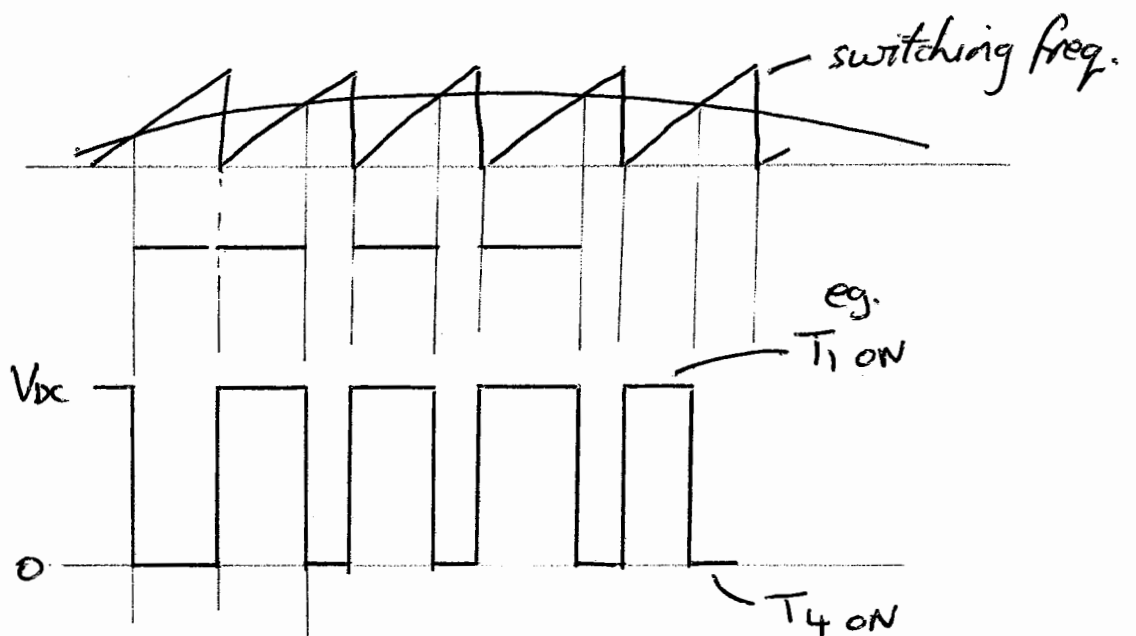
$$= \underline{1.38A} \quad (\text{Repetitive})$$

In the question as originally posed, the LiIon battery was 3.7V and the bridge gives 8.8V so a SMPS is needed for a high efficiency design, reducing the current drawn from the rectifier to $\frac{0.2 \times 3.7}{8.8} = 0.084A$.

The students all assumed a low efficiency design!

2(a) Losses on switching
Harmonics at the load / filtering.
Audibility.
Ease of generation.
Deadtime. Any three

(b) Naturally sampled - compare sawtooth to the reference sine wave. Three sine wave references are needed, displaced by $\pm 120^\circ$



The sawtooth (or triangular) wave should be an odd, integer multiple of 3 times the reference waveform frequency.

2 (c) Using the method of part (b) with Fig 2. gives a fundamental output voltage waveform $m \frac{V_{DC}}{2} \sin \omega_1 t$, where ω_1 is the angular frequency of the sinusoidal reference waveform. m is the modulation index

Since it is a three phase bridge, the outputs are similar but displaced by $\pm 120^\circ$

$$\begin{aligned} \text{rms line voltage} &= V_a - V_b \\ &= \sqrt{3} \hat{V}_a / \sqrt{2} - \text{rms} \end{aligned}$$

$$|\hat{V}_a| = m \frac{V_{DC}}{2}$$

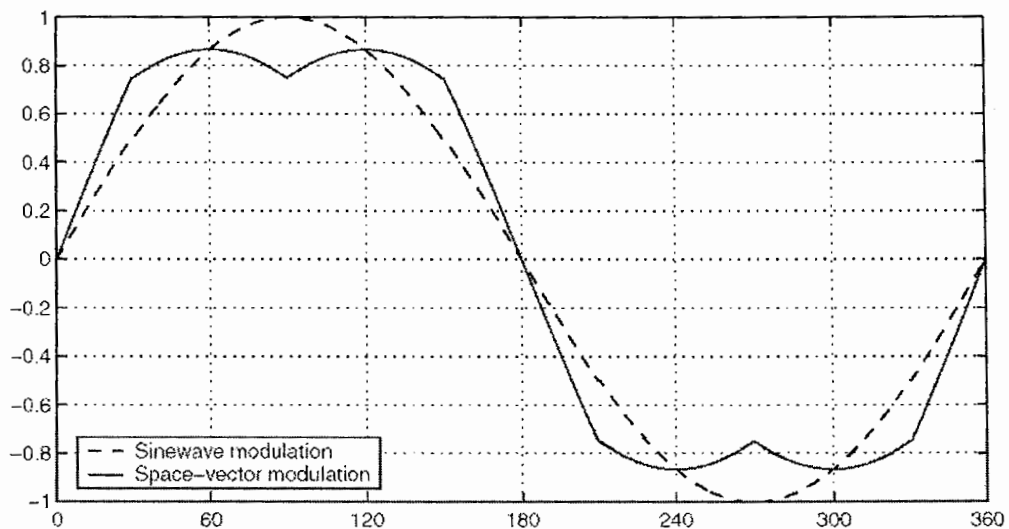
When m exceeds 1, overmodulation occurs and pulses of the output voltage are lost and the output tends to a square-wave. Thus harmonic distortion is increased. The output is no longer proportional to m .

2/(d) In space vector modulation, pulses are dropped intentionally to reduce the switching. In SVM this does not necessarily increase the harmonics or make the output non-linear with m , as the line voltage is given by $V_a - V_b$.

$$\text{ie. } P_A V_A - P_B V_B$$

Perhaps best seen in the effective reference waveform, P_A and P_B can compensate for each other, so one leg is modulating even if the other is not!

12.3.1 Comparison of the Bridge leg voltage output (filtered)



So the SVM can have a larger fundamental. Alter Sine gives a circle for the bridge; SVM gives a hexagon $2/\sqrt{3}$ ratio at the largest po

2/(d) cont.

Alter II



↑
 $V_a - V_b$ is still modulated

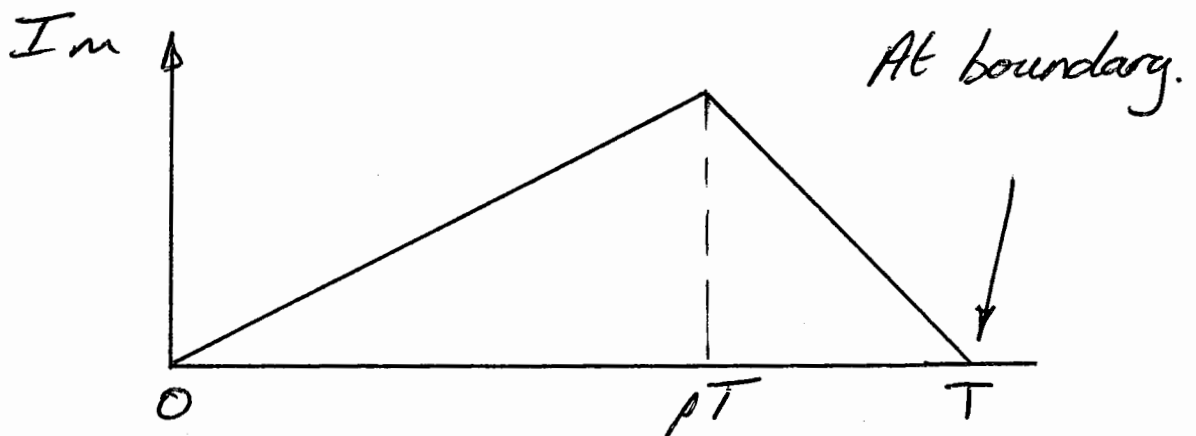
In many sinewave schemes, third-harmonics are added to the reference waveform. This has a very similar effect on the modulation linearity, although has no effect on the switching losses.

Any of the above

3/ 170V from 12V with 1:5 transformer

$\frac{170}{5}$ is reflected back so the transformer recovers with $\frac{170}{5} + 12V$ applied to the MOSFET \Rightarrow 46V

Transformer is energised by 12V



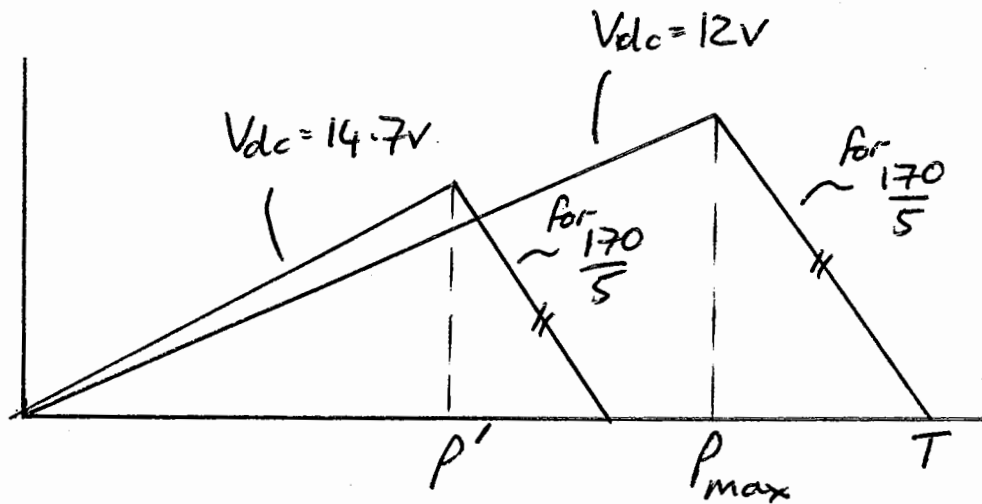
$$12pT = \frac{170}{5}(1-p)T$$

$$p = \frac{34}{46} = \underline{0.739}$$

$$100W = 0.739 \times 12 \times \frac{I}{2} \quad \frac{I}{2} = 22.55$$

A 60V, 25A Mosfet is very effective, as low voltage mosfets are very low $R_{DS(on)}$. Higher voltage Mosfets have a higher $R_{DS(on)}$ for the same area. Also the peak current here is reasonably low and losses are $I^2 R_{DS(on)}$. So 1:5 has put it in a good place for Mosfets.

3/(cont) $\frac{1}{2}$ load; 14.7V.



$$\hat{I} = \Delta i = \frac{1}{L} \int_0^{PT} V_{dc} dt = \frac{V_{dc} PT}{L} \quad \text{--- ①}$$

Energy from supply: $V \int_0^{PT} I dt = V \frac{\hat{I}}{2} PT$

$$12 \frac{\hat{I}}{2} 0.739T = 2 \times \frac{\hat{I}'}{2} P' T \cdot 14.7$$

$$\text{①} \Rightarrow 12^2 \cdot 0.739^2 = 2 \cdot 14.7^2 P'^2$$

$$P' = \frac{1}{\sqrt{2}} \cdot \frac{12}{14.7} \times 0.739 = \underline{0.43}$$

Noting that $\frac{1}{2} L \hat{I}^2$ is transferred each cycle

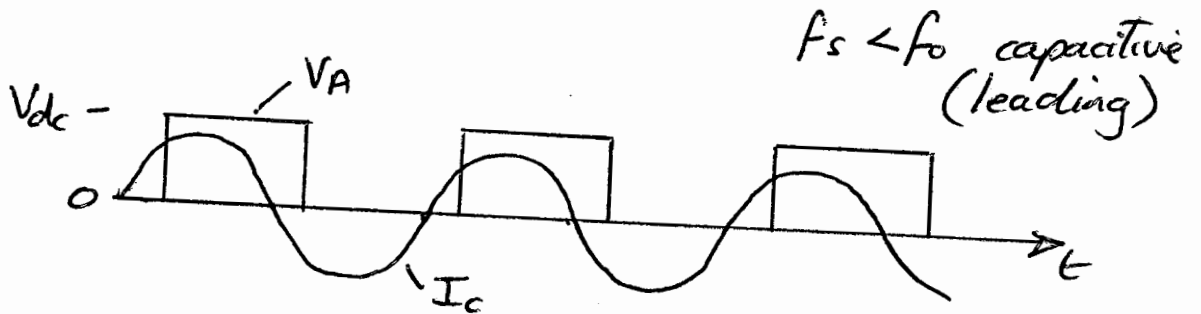
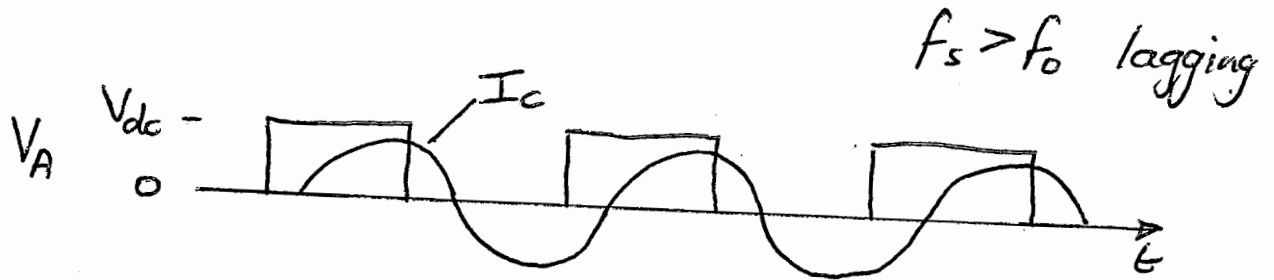
$$\frac{1}{4} L \hat{I}^2 = \frac{1}{2} L \hat{I}'^2 \quad \therefore \hat{I}' = \frac{\hat{I}}{\sqrt{2}} \text{ then use ①}$$

Similar triangles for the 170V side would also give this result.

4(a)

NOT TO BE
TAKEN OUT

LIBRARY
ENGINEERING DEPARTMENT
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$f_s > f_o$ Hard switched turn off; No diode recovery problem

$f_s = f_o$ ZCS, at turn on and off; no power control by modulation.

$f_s < f_o$ No turn-off losses; Diode recovery currents

The extra capacitor is only for $f_s > f_o$, when the capacitor acts to take the current from the switching device at turn off. The capacitor needs to be small to not affect f_o .

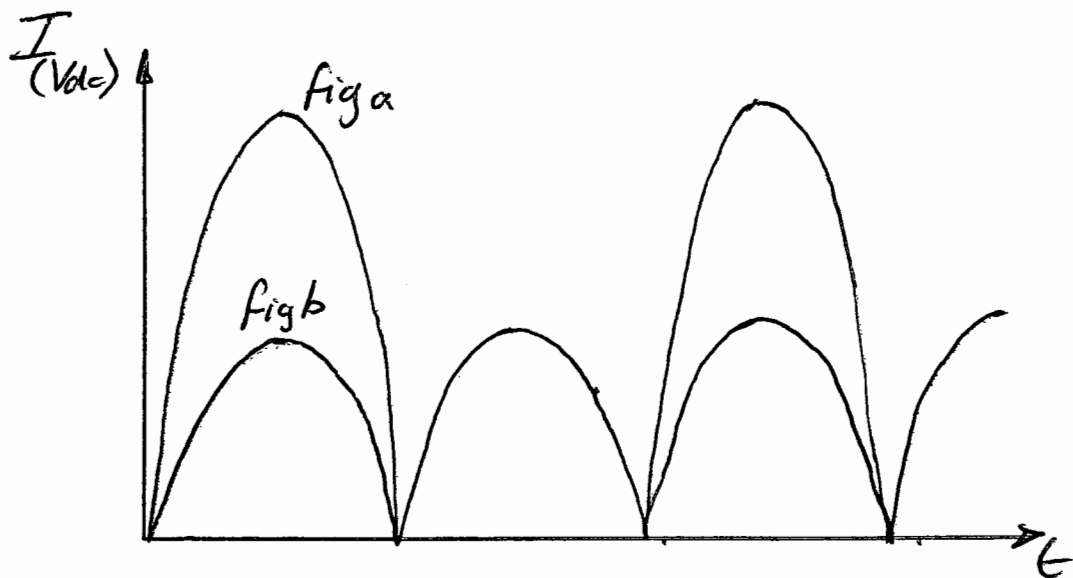
4/a) cont.

10% of C will hardly affect f_0 as
 $f_0 = \frac{1}{\sqrt{LC}} = \frac{1}{\sqrt{LC \times 1.1}}$; Similarly with Q

$$\text{Choose } 0.1C = \underline{0.01 \mu\text{F}}$$

(b) We are interested in the ac operation:

The two capacitors act in parallel: $\therefore C' = \underline{0.05 \mu\text{F}}$



$$Z_0 = \sqrt{\frac{L}{C}} = \sqrt{\frac{1}{0.1}} = 3.3 \Omega \quad \omega_0 = \frac{1}{\sqrt{LC}} = \frac{1}{\mu\sqrt{0.1}}$$

$$Q = \frac{\omega_0 L}{R} = \frac{Z_0}{R} = 3.3 \quad \text{Good filtering action!}$$

$$\text{fig b} \quad V_{ac} = \frac{48}{2} \cdot \frac{4}{\pi} = 30.56 \Rightarrow \underline{30.56 \text{ A}}$$

$$\therefore \text{for fig b } \underline{61.12 \text{ A}}$$

PTTA: 3B3: Switch mode
Electrics
2006.

6

(Principal assessor:
Dr P. R. Palmer)

ANSWERS

1.(a) 8.46 ms 17.72 Ω

(b) 2.14 ms 1.38 A

2.

3. 0.739 22.55 A 46 V 0.43

4.(a) 0.01 μF

(b) 0.05 μF 61.12 A (a) 30.56 A (b)